NSN 5962-01-226-4356

Memory Microcircuit - Page 1 of 2



time, high to low level

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Body Leng	h:
0.840 inche	3
Body Width	:
Between 0.2	20 inches and 0.310 inches
Body Heigh	it:
0.185 inche	3
Maximum F	ower Dissipation Rating:
794.0 milliw	atts
Operating 7	empurature Range:
-55.0/+125.0) degrees celsius
Storage Te	npurature Range:
-65.0/+150.0) degrees celsius
End Applic	ation:
An/bps14to	5e
Features P	ovided:
Hermetically	sealed and burn in and programmable and bipolar and schottky
Inclosure N	laterial:
Ceramic	
Inclosure C	onfiguration:
Dual-in-line	
Output Log	ic Form:
Transistor-ti	ansistor logic
Input Circu	it Pattern:
10 input	
Case Outlin	e Source And Designator:
D-2 mil-m-3	3510
Terminal S	urface Treatment:
Solder	
Voltage Ra	ing And Type Per Characteristic:
-0.5 volts p	ower source and 7.0 volts power source
Time Ratin	g Per Chacteristic:
85.00 nanos	econds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay tim
output	
Memory De	vice Type:
Prom	
Memory Ca	pacity:
Unknown	
Test Data D	ocument:
96906-mil-s	d-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal T	/pe And Quantity:
16 printed c	rcuit
Shelf Life:	
N/a	

NSN 5962-01-226-4356

Memory Microcircuit - Page 2 of 2

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

